National Semiconductor

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LMF100
High Performance Dual Switched Capacitor Filter

General Description

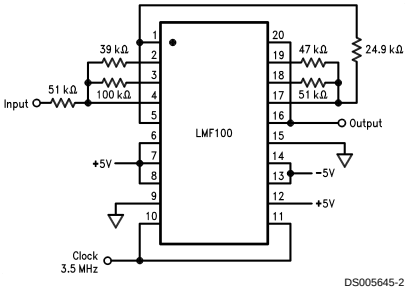
The LMF100 consists of two independent general purpose high performance switched capacitor filters. With an external clock and 2 to 4 resistors, various second-order and first-order filtering functions can be realized by each filter block. Each block has 3 outputs. One output can be configured to perform either an allpass, highpass, or notch function. The other two outputs perform bandpass and lowpass functions. The center frequency of each filter stage is tuned by using an external clock or a combination of a clock and resistor ratio. Up to a 4th-order biquadratic function can be realized with a single LMF100. Higher order filters are implemented by simply cascading additional packages, and all the classical filters (such as Butterworth, Bessel, Elliptic, and Chebyshev) can be realized.

The LMF100 is fabricated on National Semiconductor's high performance analog silicon gate CMOS process, LMCMOS™. This allows for the production of a very low offset, high frequency filter building block. The LMF100 is pin-compatible with the industry standard MF10, but provides greatly improved performance.

Features

- Wide 4V to 15V power supply range
- Operation up to 100 kHz
- Low offset voltage: typically
  (50:1 or 100:1 mode): Vos1 = ±5 mV
  Vos2 = ±15 mV
  Vos3 = ±15 mV
- Low crosstalk −60 dB
- Clock to center frequency ratio accuracy ±0.2% typical
- f_0 x Q range up to 1.8 MHz
- Pin-compatible with MF10

4th Order 100 kHz Butterworth Lowpass Filter



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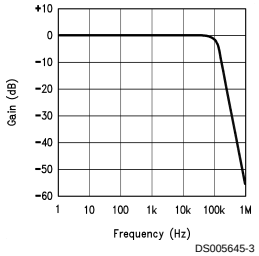

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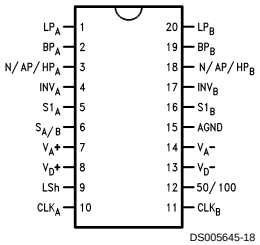
Connection Diagram

Surface Mount and Dual-In-Line Package



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Top View
Order Number
LMF100CCN or LMF100CIWM
See NS Package Number N20A or M20B

LMCMOS™ is a trademark of National Semiconductor Corporation.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

(Note 14)

Supply Voltage ($V^+ - V^-$)	16V
Voltage at Any Pin	$V^+ + 0.3V$
	$V^- - 0.3V$
Input Current at Any Pin (Note 2)	5 mA
Package Input Current (Note 2)	20 mA
Power Dissipation (Note 3)	500 mW
Storage Temperature	150˚C
ESD Susceptability (Note 11)	2000V
Soldering Information	
N Package: 10 sec.	260˚C
J Package: 10 sec.	300˚C
SO Package:	
Vapor Phase (60 sec.)	215˚C
Infrared (15 sec.)	220˚C

See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" (Appendix D) for other methods of soldering surface mount devices.

Operating Ratings (Note 1)

Temperature Range	$T_{MIN} \le T_A \le T_{MAX}$
LMF100CCN	$0˚C \le T_A \le +70˚C$
LMF100CIWM	$-40˚C \le T_A \le +85˚C$
Supply Voltage	$4V \le V^+ - V^- \le 15V$

Electrical Characteristics

The following specifications apply for Mode 1, Q = 10 ($R_1 = R_3 = 100k$, $R_2 = 10k$), $V^+ = +5V$ and $V^- = -5V$ unless otherwise specified. **Boldface limits apply for T_{MIN} to T_{MAX}**; all other limits $T_A = T_J = 25˚C$.

Symbol	Parameter		Conditions		LMF100CCN			LMF100CIWM			Units
					Typical (Note 8)	Tested Limit (Note 9)	Design Limit (Note 10)	Typical (Note 8)	Tested Limit (Note 9)	Design Limit (Note 10)	
I_s	Maximum Supply Current		f_{CLK} = 250 kHz No Input Signal		9	13	**13**	9	**13**		mA
f_0	Center Frequency	MIN			0.1			0.1			Hz
	Range	MAX			100			100			kHz
f_{CLK}	Clock Frequency	MIN			5.0			5.0			Hz
	Range	MAX			3.5			3.5			MHz
f_{CLK}/f_0	Clock to Center Frequency Ratio Deviation		V_{Pin12} = 5V or 0V f_{CLK} = 1 MHz		±0.2	±0.8	**±0.8**	±0.2	**±0.8**		%
$\frac{\Delta Q}{Q}$	Q Error (MAX) (Note 4)		Q = 10, Mode 1 V_{Pin12} = 5V or 0V f_{CLK} = 1 MHz		±0.5	±5	**±6**	±0.5	**±6**		%
H_{OBP}	Bandpass Gain at f_0		f_{CLK} = 1 MHz		0	±0.4	**±0.4**	0	±**0.4**		dB
H_{OLP}	DC Lowpass Gain		$R_1 = R_2$ = 10k f_{CLK} = 250 kHz		0	±0.2	**±0.2**	0	**±0.2**		dB
V_{OS1}	DC Offset Voltage (Note 5)		f_{CLK} = 250 kHz		±5.0	±15	**±15**	±5.0	**±15**		mV
V_{OS2}	DC Offset Voltage (Note 5)		f_{CLK} = 250 kHz	$S_{A/B} = V^+$	±30	±80	**±80**	±30	±**80**		mV
				$S_{A/B} = V^-$	±15	±70	**±70**	±15	±**70**		mV
V_{OS3}	DC Offset Voltage (Note 5)		f_{CLK} = 250 kHz		±15	±40	±**60**	±15	±**60**		mV
	Crosstalk (Note 6)		A Side to B Side or B Side to A Side		−60			−60			dB
	Output Noise (Note 12)		f_{CLK} = 250 kHz	N	40			40			µV
			20 kHz Bandwidth	BP	320			320			
			100:1 Mode	LP	300			300			
	Clock Feedthrough (Note 13)		f_{CLK} = 250 kHz 100:1 Mode		6			6			mV
V_{OUT}	Minimum Output Voltage Swing		R_L = 5k (All Outputs)		+4.0 −4.7	±3.8	**±3.7**	+4.0 −4.7	**±3.7**		V
			R_L = 3.5k (All Outputs)		+3.9 −4.6			+3.9 −4.6			V
GBW	Op Amp Gain BW Product				5			5			MHz
SR	Op Amp Slew Rate				20			20			V/µs
I_{sc}	Maximum Output Short	Source	(All Outputs)		12			12			mA
	Circuit Current (Note 7)	Sink			45			45			mA

Electrical Characteristics (Continued)

The following specifications apply for Mode 1, Q = 10 (R_1 = R_3 = 100k, R_2 = 10k), V^+ = +5V and V^- = −5V unless otherwise specified. **Boldface limits apply for T_{MIN} to T_{MAX}**; all other limits T_A = T_J = 25˚C.

Symbol	Parameter	Conditions	LMF100CCN			LMF100CIWM			Units
			Typical (Note 8)	Tested Limit (Note 9)	Design Limit (Note 10)	Typical (Note 8)	Tested Limit (Note 9)	Design Limit (Note 10)	
I_{IN}	Input Current on Pins: 4, 5, 6, 9, 10, 11, 12, 16, 17			10			**10**		µA

Electrical Characteristics

The following specifications apply for Mode 1, Q = 10 (R_1 = R_3 = 100k, R_2 = 10k), V^+ = +2.50V and V^- = −2.50V unless otherwise specified. **Boldface limits apply for T_{MIN} to T_{MAX}**; all other limits T_A = T_J = 25˚C.

Symbol	Parameter		Conditions		LMF100CCN			LMF100CIWM			Units
					Typical (Note 8)	Tested Limit (Note 9)	Design Limit (Note 10)	Typical (Note 8)	Tested Limit (Note 9)	Design Limit (Note 10)	
I_s	Maximum Supply Current		f_{CLK} = 250 kHz No Input Signal		8	12	**12**	8	**12**		mA
f_0	Center Frequency	MIN			0.1			0.1			Hz
	Range	MAX			50			50			kHz
f_{CLK}	Clock Frequency	MIN			5.0			5.0			Hz
	Range	MAX			1.5			1.5			MHz
f_{CLK}/f_0	Clock to Center Frequency Ratio Deviation		V_{Pin12} = 2.5V or 0V f_{CLK} = 1 MHz		±0.2	±1	**±1**	±0.2	**±1**		%
$\frac{\Delta Q}{Q}$	Q Error (MAX) (Note 4)		Q = 10, Mode 1 V_{Pin12} = 5V or 0V f_{CLK} = 1 MHz		±0.5	±5	**±8**	±0.5	**±8**		%
H_{OBP}	Bandpass Gain at f_0		f_{CLK} = 1 MHz		0	±0.4	**±0.5**	0	**±0.5**		dB
H_{OLP}	DC Lowpass Gain		R_1 = R_2 = 10k f_{CLK} = 250 kHz		0	±0.2	**±0.2**	0	**±0.2**		dB
V_{OS1}	DC Offset Voltage (Note 5)		f_{CLK} = 250 kHz		±5.0	±15	**±15**	±5.0	**±15**		mV
V_{OS2}	DC Offset Voltage (Note 5)		f_{CLK} = 250 kHz	$S_{A/B}$ = V^+	±20	±60	**±60**	±20	**±60**		mV
				$S_{A/B}$ = V^-	±10	±50	**±60**	±10	**±60**		mV
V_{OS3}	DC Offset Voltage (Note 5)		f_{CLK} = 250 kHz		±10	±25	**±30**	±10	**±30**		mV
	Crosstalk (Note 6)		A Side to B Side or B Side to A Side		−65			−65			dB
	Output Noise (Note 12)		f_{CLK} = 250 kHz	N	25			25			µV
			20 kHz Bandwidth	BP	250			250			
			100:1 Mode	LP	220			220			
	Clock Feedthrough (Note 13)		f_{CLK} = 250 kHz 100:1 Mode		2			2			mV
V_{OUT}	Minimum Output Voltage Swing		R_L = 5k (All Outputs)		+1.6 −2.2	±1.5	**±1.4**	+1.6 −2.2	**±1.4**		V
			R_L = 3.5k (All outputs)		+1.5 −2.1			+1.5 −2.1			V
GBW	Op Amp Gain BW Product				5			5			MHz
SR	Op Amp Slew Rate				18			18			V/µs
I_{sc}	Maximum Output Short Circuit Current (Note 7)	Source	(All Outputs)		10			10			mA
		Sink			20			20			mA

Logic Input Characteristics

Boldface limits apply for T_{MIN} to T_{MAX}; all other limits $T_A = T_J = 25^\circ C$.

Parameter		Conditions	LMF100CCN			LMF100CIWM			Units
			Typical (Note 8)	Tested Limit (Note 9)	Design Limit (Note 10)	Typical (Note 8)	Tested Limit (Note 9)	Design Limit (Note 10)	
CMOS Clock Input Voltage	MIN Logical "1"	$V^+ = +5V$, $V^- = -5V$,		+3.0	**+3.0**		**+3.0**		V
	MAX Logical "0"	$V_{LSh} = 0V$		−3.0	**−3.0**		**−3.0**		V
	MIN Logical "1"	$V^+ = +10V$, $V^- = 0V$,		+8.0	**+8.0**		**+8.0**		V
	MAX Logical "0"	$V_{LSh} = +5V$		+2.0	**+2.0**		**+2.0**		V
TTL Clock Input Voltage	MIN Logical "1"	$V^+ = +5V$, $V^- = -5V$,		+2.0	**+2.0**		**+2.0**		V
	MAX Logical "0"	$V_{LSh} = 0V$		+0.8	**+0.8**		**+0.8**		V
	MIN Logical "1"	$V^+ = +10V$, $V^- = 0V$,		+2.0	**+2.0**		**+2.0**		V
	MAX Logical "0"	$V_{LSh} = 0V$		+0.8	**+0.8**		**+0.8**		V
CMOS Clock Input Voltage	MIN Logical "1"	$V^+ = +2.5V$, $V^- = -2.5V$,		+1.5	**+1.5**		**+1.5**		V
	MAX Logical "0"	$V_{LSh} = 0V$		−1.5	**−1.5**		**−1.5**		V
	MIN Logical "1"	$V^+ = +5V$, $V^- = 0V$,		+4.0	**+4.0**		**+4.0**		V
	MAX Logical "0"	$V_{LSh} = +2.5V$		+1.0	**+1.0**		**+1.0**		V
TTL Clock Input Voltage	MIN Logical "1"	$V^+ = +5V$, $V^- = 0V$,		+2.0	**+2.0**		**+2.0**		V
	MAX Logical "0"	$V_{LSh} = 0V$, $V_D{}^+ = 0V$		+0.8	**+0.8**		**+0.8**		V

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional. These ratings do not guarantee specific performance limits, however. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.

Note 2: When the input voltage (V_{IN}) at any pin exceeds the power supply rails ($V_{IN} < V^-$ or $V_{IN} > V^+$) the absolute value of current at that pin should be limited to 5 mA or less. The sum of the currents at all pins that are driven beyond the power supply voltages should not exceed 20 mA.

Note 3: The maximum power dissipation must be derated at elevated temperatures and is dictated by T_{JMAX}, θ_{JA}, and the ambient temperature, T_A. The maximum allowable power dissipation at any temperature is $P_D = (T_{JMAX} - T_A)/\theta_{JA}$ or the number given in the Absolute Maximum Ratings, whichever is lower. For this device, $T_{JMAX} = 125^\circ C$, and the typical junction-to-ambient thermal resistance of the LMF100CIN when board mounted is $55^\circ C/W$. For the LMF100CIWM this number is $66^\circ C/W$.

Note 4: The accuracy of the Q value is a function of the center frequency (f_0). This is illustrated in the curves under the heading "Typical Peformance Characteristics".

Note 5: V_{os1}, V_{os2}, and V_{os3} refer to the internal offsets as discussed in the Applications Information section 3.4.

Note 6: Crosstalk between the internal filter sections is measured by applying a 1 V_{RMS} 10 kHz signal to one bandpass filter section input and grounding the input of the other bandpass filter section. The crosstalk is the ratio between the output of the grounded filter section and the 1 V_{RMS} input signal of the other section.

Note 7: The short circuit source current is measured by forcing the output that is being tested to its maximum positive voltage swing and then shorting that output to the negative supply. The short circuit sink current is measured by forcing the output that is being tested to its maximum negative voltage swing and then shorting that output to the positive supply. These are the worst case conditions.

Note 8: Typicals are at $25^\circ C$ and represent most likely parametric norm.

Note 9: Tested limits are guaranteed to National's AOQL (Average Outgoing Quality Level).

Note 10: Design limits are guaranteed to National's AOQL (Average Outgoing Quality Level) but are not 100% tested.

Note 11: Human body model, 100 pF discharged through a 1.5 kΩ resistor.

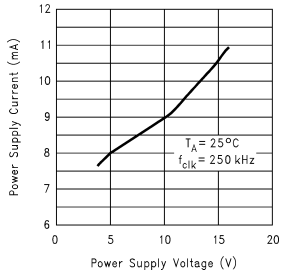
Note 12: In 50:1 mode the output noise is 3 dB higher.

Note 13: In 50:1 mode the clock feedthrough is 6 dB higher.

Note 14: A military RETS specification is available upon request.

Typical Performance Characteristics

Power Supply Current vs Power Supply Voltage



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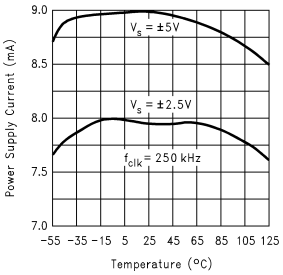
Power Supply Current vs Temperature



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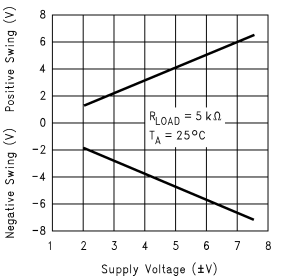
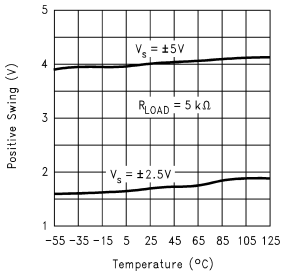
Output Swing vs Supply Voltage



DS005645-42

Positive Output Swing vs Temperature



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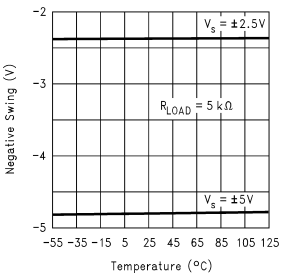
Negative Output Swing vs Temperature



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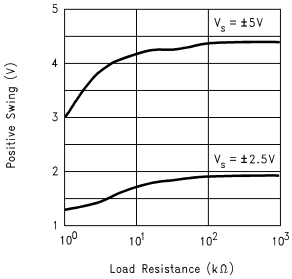
Positive Output Voltage Swing vs Load Resistance



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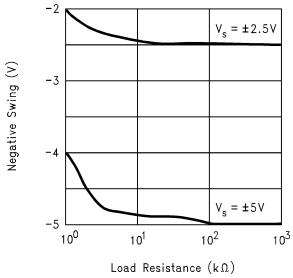
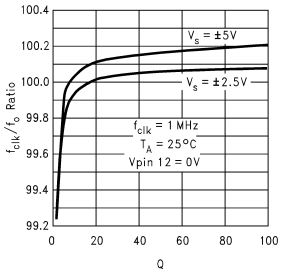
Negative Output Voltage Swing vs Load Resistance



DS005645-46

f_{CLK}/f_0 Ratio vs Q



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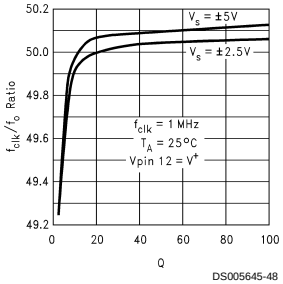
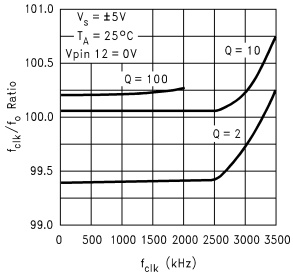
f_{CLK}/f_0 Ratio vs Q



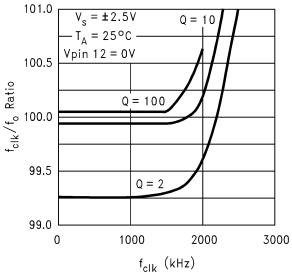
DS005645-48

f_{CLK}/f_0 Ratio vs f_{CLK}



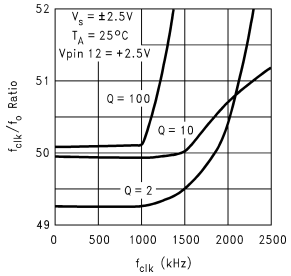
DS005645-49

f_{CLK}/f_0 Ratio vs f_{CLK}



DS005645-50

f_{CLK}/f_0 Ratio vs f_{CLK}



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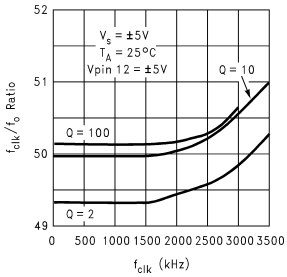
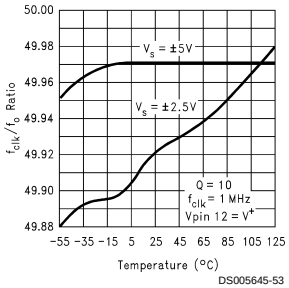
Typical Performance Characteristics (Continued)

f_{CLK}/f_0 Ratio vs f_{CLK}



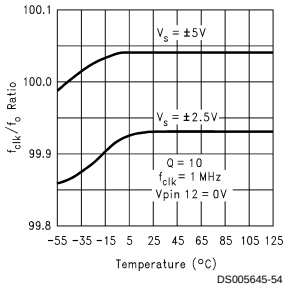
DS005645-52

f_{CLK}/f_0 Ratio vs Temperature



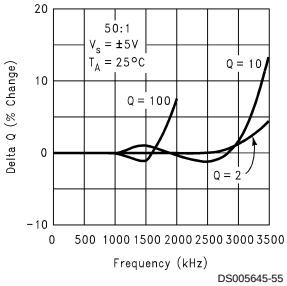
DS005645-53

f_{CLK}/f_0 Ratio vs Temperature



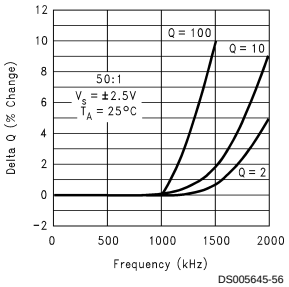
DS005645-54

Q Deviation vs Clock Frequency



DS005645-55

Q Deviation vs Clock Frequency



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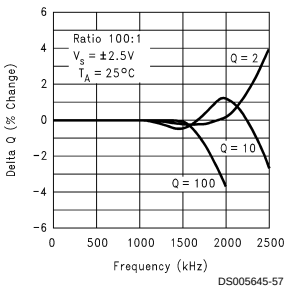
Q Deviation vs Clock Frequency



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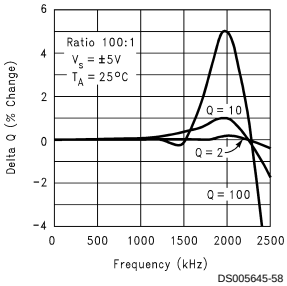
Q Deviation vs Clock Frequency



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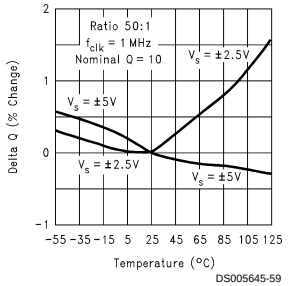
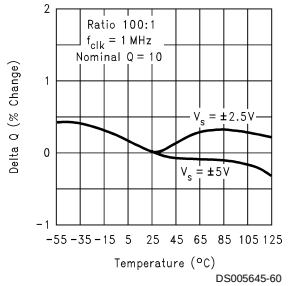
Q Deviation vs Temperature



DS005645-59

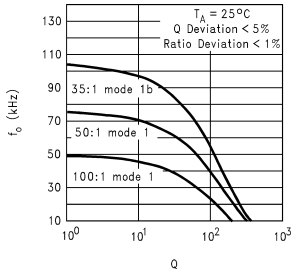
Q Deviation vs Temperature



DS005645-60

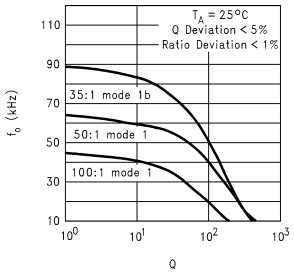
Typical Performance Characteristics (Continued)

Maximum f_0 vs Q at V_s = ±7.5V



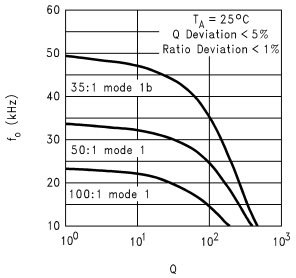
DS005645-61

Maximum f_0 vs Q at V_s = ±5.0V



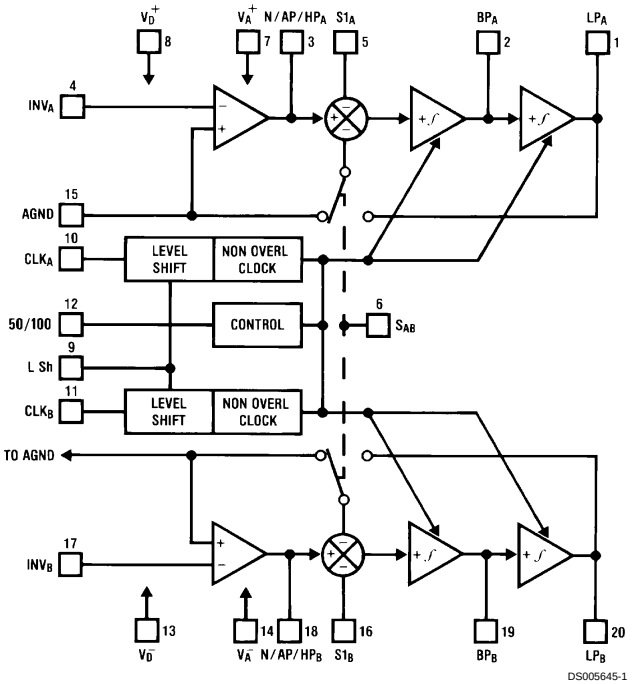
DS005645-62

Maximum f_0 vs Q at V_s = ±2.5V



DS005645-63

LMF100 System Block Diagram



DS005645-1

Pin Descriptions

LP(1,20), BP(2,19), N/AP/HP(3,18)	The second order lowpass, bandpass and notch/allpass/highpass outputs. These outputs can typically swing to within 1V of each supply when driving a 5 kΩ load. For optimum performance, capacitive loading on these outputs should be minimized. For signal frequencies above 15 kHz the capacitance loading should be kept below 30 pF.
INV(4,17)	The inverting input of the summing opamp of each filter. These are high impedance inputs. The non-inverting input is internally tied to AGND so the opamp can be used only as an inverting amplifier.
S1(5,16)	S1 is a signal input pin used in modes 1b, 4, and 5. The input impedance is $1/f_{CLK}$ x 1 pF. The pin should be driven with a source impedance of less than 1 kΩ. If S1 is not driven with a signal it should be tied to AGND (mid-supply).
$S_{A/B}$(6)	This pin activates a switch that connects one of the inputs of each filter's second summer either to AGND ($S_{A/B}$ tied to V^-) or to the lowpass (LP) output ($S_{A/B}$ tied to V^+). This offers the flexibility needed for configuring the filter in its various modes of operation.
V_A^+(7) (Note 15)	This is both the analog and digital positive supply.
V_D^+(8) (Note 15)	This pin needs to be tied to V^+ except when the device is to operate on a single 5V supply and a TTL level clock is applied. For 5V, TTL operation, V_D^+ should be tied to ground (0V).
V_A^-(14), V_D^-(13)	Analog and digital negative supplies. $V_A^-$and V_D^- should be derived from the same source. They have been brought out separately so they can be bypassed by separate capacitors, if desired. They can also be tied together externally and bypassed with a single capacitor.
LSh(9)	Level shift pin. This is used to accommodate various clock levels with dual or single supply operation. With dual ±5V supplies and CMOS (±5V) or TTL (0V–5V) clock levels, LSh should be tied to system ground. For 0V–10V single supply operation the AGND pin should be biased at +5V and the LSh pin should be tied to the system ground for TTL clock levels. LSh should be biased at +5V for ±5V CMOS clock levels. The LSh pin is tied to system ground for ±2.5V operation. For single 5V operation the LSh and V_D+ pins are tied to system ground for TTL clock levels.
CLK(10,11)	Clock inputs for the two switched capacitor filter sections. Unipolar or bipolar clock levels may be applied to the CLK inputs according to the programming voltage applied to the LSh pin. The duty cycle of the clock should be close to 50%, especially when clock frequencies above 200 kHz are used. This allows the maximum time for the internal opamps to settle, which yields optimum filter performance.
50/100(12) (Note 15)	By tying this pin to V^+ a 50:1 clock to filter center frequency ratio is obtained. Tying this pin at mid-supply (i.e., system ground with dual supplies) or to V^- allows the filter to operate at a 100:1 clock to center frequency ratio.
AGND(15)	This is the analog ground pin. This pin should be connected to the system ground for dual supply operation or biased to mid-supply for single supply operation. For a further discussion of mid-supply biasing techniques see the Applications Information (Section 3.2). For optimum filter performance a "clean" ground must be provided.

Note 15: This device is pin-for-pin compatible with the MF10 except for the following changes:

1. Unlike the MF10, the LMF100 has a single positive supply pin (V_A+).

2. On the LMF100 V_D^+ is a control pin and is not the digital positive supply as on the MF10.

3. Unlike the MF10, the LMF100 does not support the current limiting mode. When the 50/100 pin is tied to V^- the LMF100 will remain in the 100:1 mode.

1.0 Definitions of Terms

f_{CLK}: the frequency of the external clock signal applied to pin 10 or 11.

f_0: center frequency of the second order function complex pole pair. f_0 is measured at the bandpass outputs of the LMF100, and is the frequency of maximum bandpass gain. (*Figure 1*).

f_{notch}: the frequency of minimum (ideally zero) gain at the notch outputs.

f_z: the center frequency of the second order complex zero pair, if any. If f_z is different from f_0 and if Q_z is high, it can be observed as the frequency of a notch at the allpass output. (*Figure 13*).

Q: "quality factor" of the 2nd order filter. Q is measured at the bandpass outputs of the LMF100 and is equal to f_0 divided by the −3 dB bandwidth of the 2nd order bandpass filter (*Figure 1*). The value of Q determines the shape of the 2nd order filter responses as shown in *Figure 6*.

Q_z: the quality factor of the second order complex zero pair, if any. Q_Z is related to the allpass characteristic, which is written:

$$H_{AP}(s) = \frac{H_{OAP}\left(s^2 - \frac{s\omega_o}{Q_z} + \omega_o{}^2\right)}{s^2 + \frac{s\omega_o}{Q} + \omega_o{}^2}$$

where $Q_Z = Q$ for an all-pass response.

H_{OBP}: the gain (in V/V) of the bandpass output at $f = f_0$.

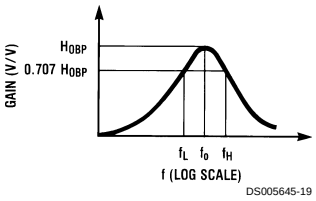
H_{OLP}: the gain (in V/V) of the lowpass output as $f \rightarrow 0$ Hz (*Figure 2*).

H_{OHP}: the gain (in V/V) of the highpass output as $f \rightarrow f_{CLK}/2$ (*Figure 3*).

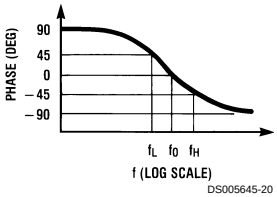
H_{ON}: the gain (in V/V) of the notch output as $f \rightarrow 0$ Hz and as $f \rightarrow f_{CLK}/2$, when the notch filter has equal gain above and below the center frequency (*Figure 4*). When the low-frequency gain differs from the high-frequency gain, as in modes 2 and 3a (*Figure 10* and *Figure 12*), the two quantities below are used in place of H_{ON}.

H_{ON1}: the gain (in V/V) of the notch output as $f \rightarrow 0$ Hz.

H_{ON2}: the gain (in V/V) of the notch output as $f \rightarrow f_{CLK}/2$.



(a)



(b)

$$H_{BP}(s) = \frac{\frac{\omega_O}{Q}s}{s^2 + \frac{s\omega_o}{Q} + \omega_o{}^2}$$

$$Q = \frac{f_0}{f_H - f_L};\ f_0 = \sqrt{f_L f_H}$$

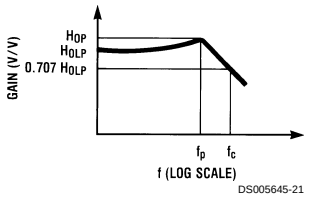
$$f_L = f_0\left(\frac{-1}{2Q} + \sqrt{\left(\frac{1}{2Q}\right)^2 + 1}\right)$$

$$f_H = f_0\left(\frac{1}{2Q} + \sqrt{\left(\frac{1}{2Q}\right)^2 + 1}\right)$$

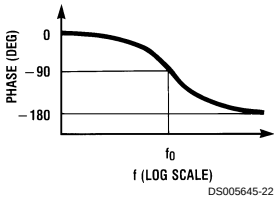
$$\omega_o = 2\pi f_0$$

FIGURE 1. 2nd-Order Bandpass Response

1.0 Definitions of Terms (Continued)



(a)



(b)

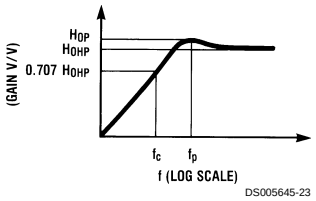
$$H_{LP}(s) = \frac{H_{OLP}\omega_O^2}{s^2 + \frac{s\omega_o}{Q} + \omega_o^2}$$

$$f_c = f_0 \times \sqrt{\left(1 - \frac{1}{2Q^2}\right) + \sqrt{\left(1 - \frac{1}{2Q^2}\right)^2 + 1}}$$

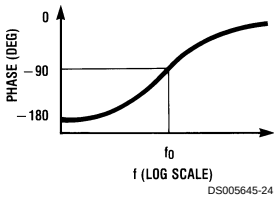
$$f_p = f_0 \sqrt{1 - \frac{1}{2Q^2}}$$

$$H_{OP} = H_{OLP} \times \frac{1}{\frac{1}{Q}\sqrt{1 - \frac{1}{4Q^2}}}$$

FIGURE 2. 2nd-Order Low-Pass Response



(a)



(b)

$$H_{HP}(s) = \frac{H_{OHP}s^2}{s^2 + \frac{s\omega_o}{Q} + \omega_o^2}$$

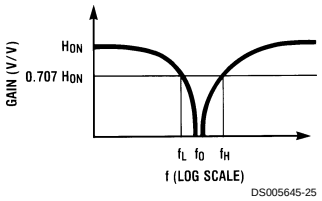
$$f_c = f_0 \times \left[\sqrt{\left(1 - \frac{1}{2Q^2}\right) + \sqrt{\left(1 - \frac{1}{2Q^2}\right)^2 + 1}}\right]^{-1}$$

$$f_p = f_0 \times \left[\sqrt{1 - \frac{1}{2Q^2}}\right]^{-1}$$

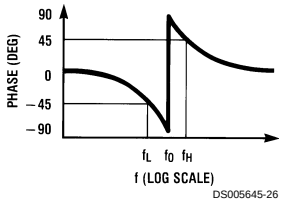
$$H_{OP} = H_{OHP} \times \frac{1}{\frac{1}{Q}\sqrt{1 - \frac{1}{4Q^2}}}$$

FIGURE 3. 2nd-Order High-Pass Response

1.0 Definitions of Terms (Continued)



(a)



(b)

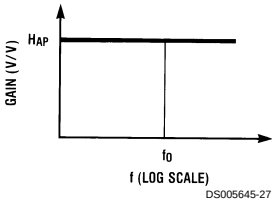
$$H_N(s) = \frac{H_{ON}(s^2 + \omega_o^2)}{s^2 + \frac{s\omega_o}{Q} + \omega_o^2}$$

$$Q = \frac{f_0}{f_H - f_L};\ f_0 = \sqrt{f_L f_H}$$

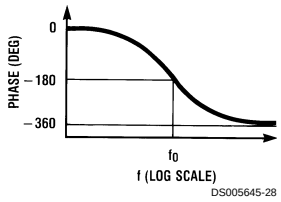
$$f_L = f_0\left(\frac{-1}{2Q} + \sqrt{\left(\frac{1}{2Q}\right)^2 + 1}\right)$$

$$f_H = f_0\left(\frac{1}{2Q} + \sqrt{\left(\frac{1}{2Q}\right)^2 + 1}\right)$$

FIGURE 4. 2nd-Order Notch Response



(a)



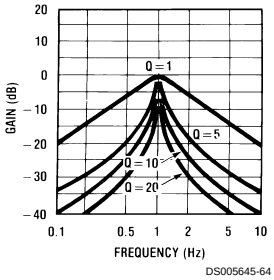
(b)

$$H_{AP}(s) = \frac{H_{OAP}\left(s^2 - \frac{s\omega_o}{Q} + \omega_o^2\right)}{s^2 + \frac{s\omega_o}{Q} + \omega_o^2}$$

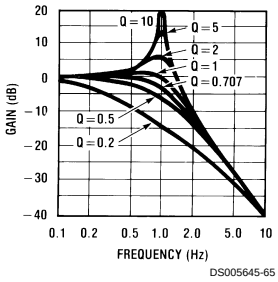
FIGURE 5. 2nd-Order All-Pass Response

1.0 Definitions of Terms (Continued)

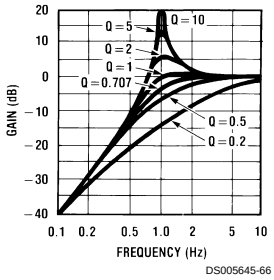
(a) Bandpass



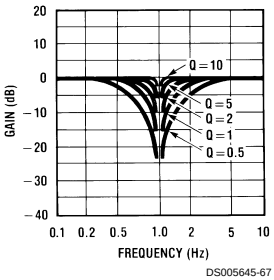
(b) Low Pass



(c) High-Pass



(d) Notch



(e) All-Pass

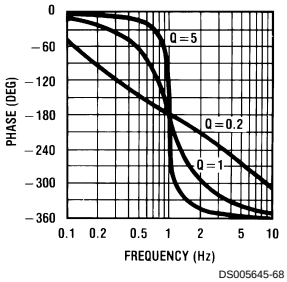


FIGURE 6. Response of various 2nd-order filters as a function of Q. Gains and center frequencies are normalized to unity.

2.0 Modes of Operation

The LMF100 is a switched capacitor (sampled data) filter. To fully describe its transfer functions, a time domain analysis is appropriate. Since this is cumbersome, and since the LMF100 closely approximates continuous filters, the following discussion is based on the well-known frequency domain. Each LMF100 can produce two full 2nd order functions. See *Table 1* for a summary of the characteristics of the various modes.

MODE 1: Notch 1, Bandpass, Lowpass Outputs:

$f_{notch} = f_0$ (See *Figure 7*)

f_0 = center frequency of the complex pole pair

$= \frac{f_{CLK}}{100}$ or $\frac{f_{CLK}}{50}$

f_{notch} = center frequency of the imaginary zero pair = f_0.

H_{OLP} = Lowpass gain (as $f \rightarrow 0$) = $-\frac{R2}{R1}$

H_{OBP} = Bandpass gain (at $f = f_0$) = $-\frac{R3}{R1}$

H_{ON} = Notch output gain as $f \rightarrow 0$, $f \rightarrow f_{CLK}/2$ $= \frac{-R_2}{R_1}$

$Q = \frac{f_0}{BW} = \frac{R3}{R2}$

= quality factor of the complex pole pair

BW = the −3 dB bandwidth of the bandpass output.

Circuit dynamics:

$H_{OLP} = \frac{H_{OBP}}{Q}$ or $H_{OBP} = H_{OLP} \times Q$

$= H_{ON} \times Q.$

$H_{OLP(peak)} \cong Q \times H_{OLP}$ (for high Q's)

MODE 1a: Non-Inverting BP, LP (See *Figure 8*)

$f_0 = \frac{f_{CLK}}{100}$ or $\frac{f_{CLK}}{50}$

$Q = \frac{R3}{R2}$

$H_{OLP} = -1$; $H_{OLP(peak)} \cong Q \times H_{OLP}$ (for high Q's)

$H_{OBP_1} = -\frac{R3}{R2}$

$H_{OBP_2} = 1$ (non-inverting)

Circuit dynamics: $H_{OBP_1} = Q$

Note: V_{IN} should be driven from a low impedance (<1 kΩ) source.

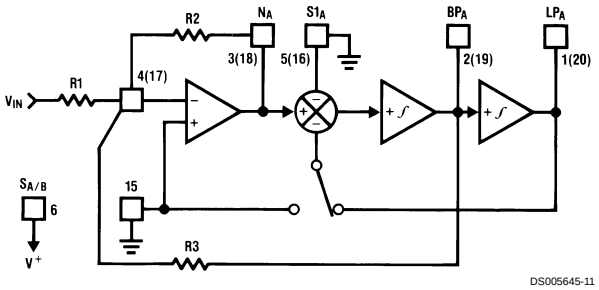


FIGURE 7. MODE 1

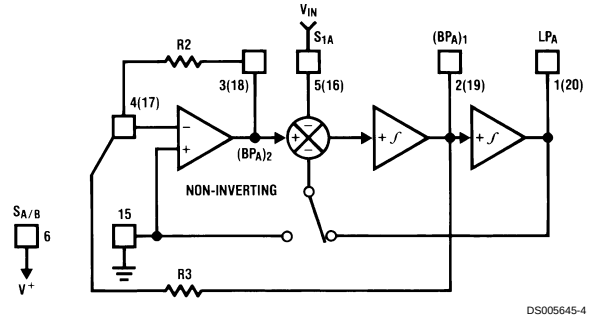


FIGURE 8. MODE 1a

2.0 Modes of Operation (Continued)

MODE 1b: Notch 1, Bandpass, Lowpass Outputs:

$f_{notch} = f_0$ (See *Figure 9*)

f_0 = center frequency of the complex pole pair

$= \frac{f_{CLK}}{100} \times \sqrt{2}$ or $\frac{f_{CLK}}{50} \times \sqrt{2}$

f_{notch} = center frequency of the imaginary zero pair = f_0.

H_{OLP} = Lowpass gain (as $f \rightarrow 0$) $= -\frac{R2}{2R1}$

H_{OBP} = Bandpass gain (at $f = f_0$) $= -\frac{R3}{R1}$

H_{ON} = Notch output gain as $\left.\begin{matrix} f \rightarrow 0 \\ f \rightarrow f_{CLK}/2 \end{matrix}\right\} = \frac{-R_2}{R_1}$

$Q = \frac{f_0}{BW} = \frac{R3}{R2} \times \sqrt{2}$

= quality factor of the complex pole pair

BW = the −3 dB bandwidth of the bandpass output.

Circuit dynamics:

$H_{OLP} = \frac{H_{OBP}}{\sqrt{2}\,Q}$ or $H_{OBP} = H_{OLP} \times Q \times \sqrt{2}$

$H_{OBP} = \frac{H_{ON} \times Q}{\sqrt{2}}$

$H_{OLP(peak)} \cong Q \times H_{OLP}$ (for high Q's)

MODE 2: Notch 2, Bandpass, Lowpass: $f_{notch} < f_0$
(See *Figure 10*)

f_0 = center frequency

$= \frac{f_{CLK}}{100}\sqrt{\frac{R2}{R4} + 1}$ or $\frac{f_{CLK}}{50}\sqrt{\frac{R2}{R4} + 1}$

$f_{notch} = \frac{f_{CLK}}{100}$ or $\frac{f_{CLK}}{50}$

Q = quality factor of the complex pole pair

$= \frac{\sqrt{R2/R4 + 1}}{R2/R3}$

H_{OLP} = Lowpass output gain (as $f \rightarrow 0$)

$= -\frac{R2/R1}{R2/R4 + 1}$

H_{OBP} = Bandpass output gain (at $f = f_0$) = − R3/R1

H_{ON_1} = Notch output gain (as $f \rightarrow 0$)

$= -\frac{R2/R1}{R2/R4 + 1}$

H_{ON_2} = Notch output gain $\left(\text{as } f \rightarrow \frac{f_{CLK}}{2}\right) = -R2/R1$

Filter dynamics: $H_{OBP} = Q\sqrt{H_{OLP}\,H_{ON_2}} = \sqrt{H_{ON_1}\,H_{ON_2}}$

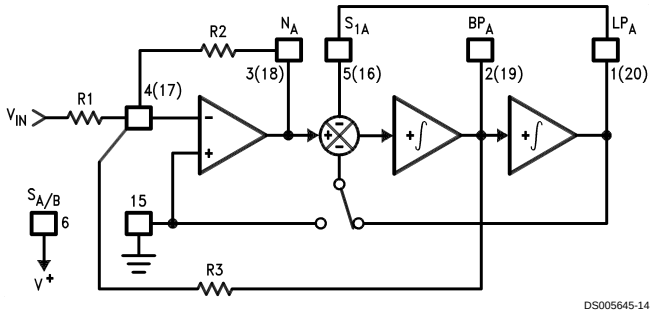


FIGURE 9. MODE 1b

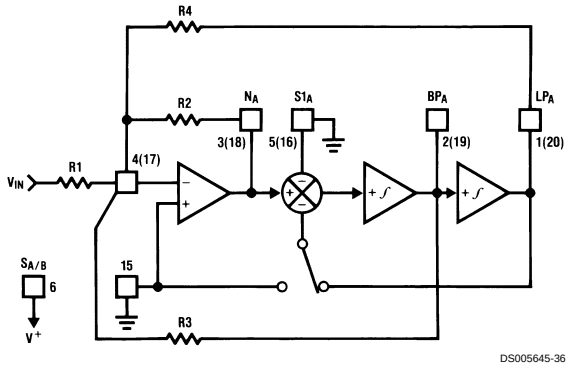


FIGURE 10. MODE 2

2.0 Modes of Operation (Continued)

MODE 3: Highpass, Bandpass, Lowpass Outputs
(See *Figure 11*)

$$f_0 = \frac{f_{CLK}}{100} \times \sqrt{\frac{R2}{R4}} \text{ or } \frac{f_{CLK}}{50} \times \sqrt{\frac{R2}{R4}}$$

$$Q = \text{quality factor of the complex pole pair} = \sqrt{\frac{R2}{R4}} \times \frac{R3}{R2}$$

$$H_{OHP} = \text{Highpass gain} \left(\text{at } f \rightarrow \frac{f_{CLK}}{2}\right) = -\frac{R2}{R1}$$

$$H_{OBP} = \text{Bandpass gain (at } f = f_0) = -\frac{R3}{R1}$$

$$H_{OLP} = \text{Lowpass gain (as } f \rightarrow 0) = -\frac{R4}{R1}$$

$$\text{Circuit dynamics: } \frac{R2}{R4} = \frac{H_{OHP}}{H_{OLP}};\ H_{OBP} = \sqrt{H_{OHP} \times H_{OLP}} \times Q$$

$$H_{OLP(peak)} \cong Q \times H_{OLP} \text{ (for high Q's)}$$

$$H_{OHP(peak)} \cong Q \times H_{OHP} \text{ (for high Q's)}$$

MODE 3a: HP, BP, LP and Notch with External Op Amp
(See *Figure 12*)

$$f_0 = \frac{f_{CLK}}{100} \times \sqrt{\frac{R2}{R4}} \text{ or } \frac{f_{CLK}}{50} \times \sqrt{\frac{R2}{R4}}$$

$$Q = \sqrt{\frac{R2}{R4}} \times \frac{R3}{R2}$$

$$H_{OHP} = -\frac{R2}{R1}$$

$$H_{OBP} = -\frac{R3}{R1}$$

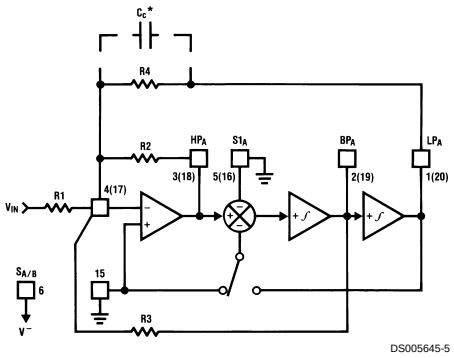
$$H_{OLP} = -\frac{R4}{R1}$$

$$f_n = \text{notch frequency} = \frac{f_{CLK}}{100} \sqrt{\frac{R_h}{R_l}} \text{ or } \frac{f_{CLK}}{50} \sqrt{\frac{R_h}{R_l}}$$

$$H_{ON} = \text{gain of notch at } f = f_0 = \left\| Q\left(\frac{R_g}{R_l} H_{OLP} - \frac{R_g}{R_h} H_{OHP}\right) \right\|$$

$$H_{n1} = \text{gain of notch (as } f \rightarrow 0) = \frac{R_g}{R_l} \times H_{OLP}$$

$$H_{n2} = \text{gain of notch} \left(\text{as } f \rightarrow \frac{f_{CLK}}{2}\right) = -\frac{R_g}{R_h} \times H_{OHP}$$



*In Mode 3, the feedback loop is closed around the input summing amplifier; the finite GBW product of this op amp causes a slight Q enhancement. If this is a problem, connect a small capacitor (10 pF−100 pF) across R4 to provide some phase lead.

FIGURE 11. MODE 3

2.0 Modes of Operation (Continued)

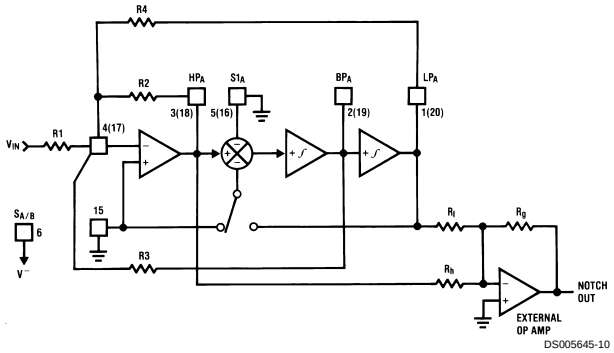


FIGURE 12. MODE 3a

MODE 4: Allpass, Bandpass, Lowpass Outputs

(See *Figure 13*)

f_0 = center frequency

$= \frac{f_{CLK}}{100}$ or $\frac{f_{CLK}}{50}$;

f_z* = center frequency of the complex zero $\approx f_0$

$Q = \frac{f_0}{BW} = \frac{R3}{R2}$;

Q_z = quality factor of complex zero pair $= \frac{R3}{R1}$

For AP output make R1 = R2

H_{OAP}* = Allpass gain $\left(\text{at } 0 < f < \frac{f_{CLK}}{2}\right) = -\frac{R2}{R1} = -1$

H_{OLP} = Lowpass gain (as $f \rightarrow 0$)

$= -\left(\frac{R2}{R1} + 1\right) = -2$

H_{OBP} = Bandpass gain (at $f = f_0$)

$= -\frac{R3}{R2}\left(1 + \frac{R2}{R1}\right) = -2\left(\frac{R3}{R2}\right)$

Circuit dynamics: $H_{OBP} = (H_{OLP}) \times Q = (H_{OAP} + 1)Q$

*Due to the sampled data nature of the filter, a slight mismatch of f_z and f_0 occurs causing a 0.4 dB peaking around f_0 of the allpass filter amplitude response (which theoretically should be a straight line). If this is unacceptable, Mode 5 is recommended.

MODE 5: Numerator Complex Zeros, BP, LP

(See *Figure 14*)

$f_0 = \sqrt{1 + \frac{R2}{R4}} \times \frac{f_{CLK}}{100}$ or $\sqrt{1 + \frac{R2}{R4}} \times \frac{f_{CLK}}{50}$

$f_z = \sqrt{1 - \frac{R1}{R4}} \times \frac{f_{CLK}}{100}$ or $\sqrt{1 - \frac{R1}{R4}} \times \frac{f_{CLK}}{50}$

$Q = \sqrt{1 + R2/R4} \times \frac{R3}{R2}$

$Q_Z = \sqrt{1 - R1/R4} \times \frac{R3}{R1}$

H_{0z1} = gain at C.Z. output (as $f \rightarrow 0$ Hz) $= \frac{-R2(R4 - R1)}{R1(R2 + R4)}$

H_{0z2} = gain at C.Z. output $\left(\text{as } f \rightarrow \frac{f_{CLK}}{2}\right) = \frac{-R2}{R1}$

$H_{OBP} = -\left(\frac{R2}{R1} + 1\right) \times \frac{R3}{R2}$

$H_{OLP} = -\left(\frac{R2 + R1}{R2 + R4}\right) \times \frac{R4}{R1}$

2.0 Modes of Operation (Continued)

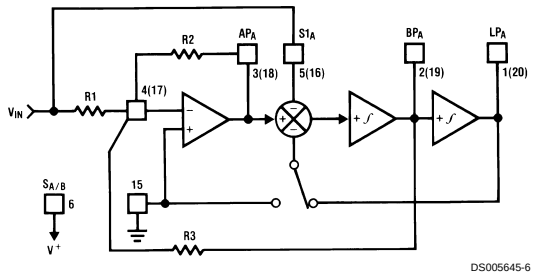


FIGURE 13. MODE 4

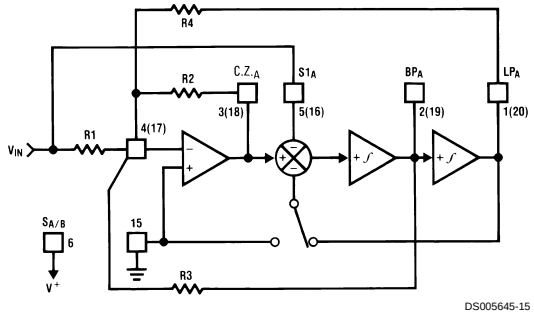


FIGURE 14. MODE 5

MODE 6a: Single Pole, HP, LP Filter (See *Figure 15*)

f_c = cutoff frequency of LP or HP output

$$= \frac{R2}{R3}\frac{f_{CLK}}{100} \text{ or } \frac{R2}{R3}\frac{f_{CLK}}{50}$$

$$H_{OLP} = -\frac{R3}{R1}$$

$$H_{OHP} = -\frac{R2}{R1}$$

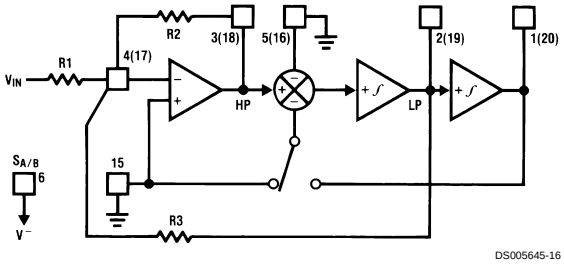


FIGURE 15. MODE 6a

2.0 Modes of Operation (Continued)

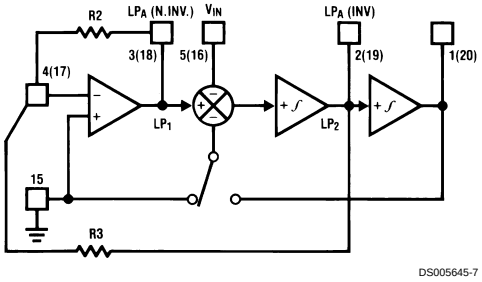


FIGURE 16. MODE 6b

MODE 6b: Single Pole LP Filter (Inverting and Non-Inverting) (See *Figure 16*)

f_c = cutoff frequency of LP outputs

$\cong \frac{R2}{R3}\frac{f_{CLK}}{100}$ or $\frac{R2}{R3}\frac{f_{CLK}}{50}$

$H_{OLP_1} = 1$ (non-inverting)

$H_{OLP_2} = -\frac{R3}{R2}$

MODE 6c: Single Pole, AP, LP Filter (See *Figure 17*)

$f_c = \frac{f_{CLK}}{50}$ or $\frac{f_{CLK}}{100}$

$H_{OAP} = 1$ (as $f \rightarrow 0$)

$H_{OAP} = -1$ (as $f \rightarrow f_{CLK}/2$)

$H_{OLP} = -2$

$R_1 = R_2 = R_3$

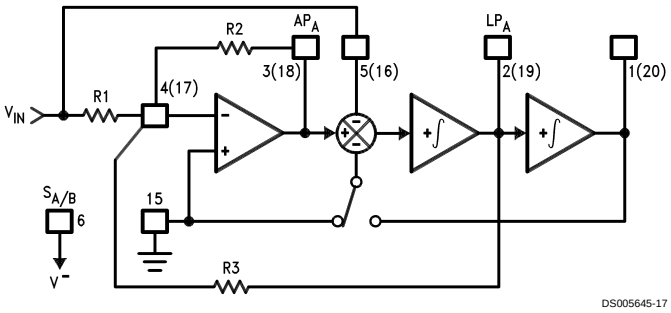
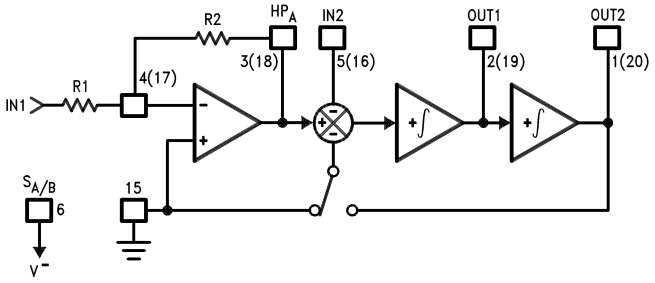
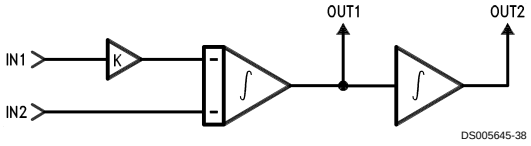


FIGURE 17. MODE 6c

2.0 Modes of Operation (Continued)



Equivalent Circuit



$$K = \frac{R_2}{R_1}$$

$$OUT1 = -\frac{k}{\tau}\int IN1\,dt - \frac{1}{\tau}\int IN2\,dt$$

$$OUT2 = \frac{1}{\tau}\int OUT1\,dt$$

FIGURE 18. MODE 7

MODE 7: Summing Integrator (See *Figure 18*)

$$\tau = \text{integrator time constant} = \frac{16}{f_{CLK}} \text{ or } \frac{8}{f_{CLK}}$$

2.0 Modes of Operation (Continued)

TABLE 1. Summary of Modes. Realizable filter types (e.g. low-pass) denoted by asterisks. Unless otherwise noted, gains of various filter outputs are inverting and adjustable by resistor ratios.

Mode	BP	LP	HP	N	AP	Number of Resistors	Adjustable f_{CLK}/f_0	Notes
1	*	*		*		3	No	
1a	(2) $H_{OBP1} = -Q$ $H_{OBP2} = +1$	$H_{OLP} = +1$				2	No	May need input buffer. Poor dynamics for high Q.
1b	*	*		*		3	No	Useful for high frequency applications.
2	*	*		*		3	Yes (above $f_{CLK}/50$ or $f_{CLK}/100$)	
3	*	*	*			4	Yes	Universal State-Variable Filter. Best general-purpose mode.
3a	*	*	*	*		7	Yes	As above, but also includes resistor-tuneable notch.
4	*	*			*	3	No	Gives Allpass response with $H_{OAP} = -1$ and $H_{OLP} = -2$.
5	*	*			*	4	Yes	Gives flatter allpass response than above if $R_1 = R_2 = 0.02R_4$.
6a		*	*			3	Yes	Single pole.
6b		(2) $H_{OLP1} = +1$ $H_{OLP2} = \frac{-R3}{R2}$				2	Yes	Single pole.
6c		*			*	3	No	Single pole.
7						2	Yes	Summing integrator with adjustable time constant.

3.0 Applications Information

The LMF100 is a general purpose dual second-order state variable filter whose center frequency is proportional to the frequency of the square wave applied to the clock input (f_{CLK}). The various clocking options are summarized in the following table.

Clocking Options

Power Supply	Clock Levels	LSh	V_D^+
−5V and +5V	TTL (0V to +5V)	0V	+5V
−5V and +5V	CMOS (−5V to +5V)	0V	+5V
0V and 10V	TTL (0V to 5V)	0V	+10V
0V and 10V	CMOS (0V to +10V)	+5V	+10V
−2.5V and +2.5V	CMOS (−2.5V to +2.5V)	0V	+2.5V
0V and 5V	TTL (0V to +5V)	0V	0V

Power Supply	Clock Levels	LSh	V_D^+
0V and 5V	CMOS (0V to +5V)	+2.5V	+5V

By connecting pin 12 to the appropriate dc voltage, the filter center frequency, f_0, can be made equal to either $f_{CLK}/100$ or $f_{CLK}/50$. f_0 can be very accurately set (within ±0.6%) by using a crystal clock oscillator, or can be easily varied over a wide frequency range by adjusting the clock frequency. If desired, the f_{CLK}/f_0 ratio can be altered by external resistors as in *Figures 10, 11, 12, 13, 14, 15* and *Figure 16*. This is useful when high-order filters (greater than two) are to be realized by cascading the second-order sections. This allows each stage to be stagger tuned while using only one clock. The filter Q and gain are set by external resistor ratios.

All of the five second-order filter types can be built using either section of the LMF100. These are illustrated in *Figures 1, 2, 3, 4* and *Figure 5* along with their transfer functions and some related equations. *Figure 6* shows the effect of Q on the shapes of these curves.

3.0 Applications Information

(Continued)

3.1 DESIGN EXAMPLE

In order to design a filter using the LMF100, we must define the necessary values of three parameters for each second-order section: f_0, the filter section's center frequency; H_0, the passband gain; and the filter's Q. These are determined by the characteristics required of the filter being designed.

As an example, let's assume that a system requires a fourth-order Chebyshev low-pass filter with 1 dB ripple, unity gain at dc, and 1000 Hz cutoff frequency. As the system order is four, it is realizable using both second-order sections of an LMF100. Many filter design texts (and National's Switched Capacitor Filter Handbook) include tables that list the characteristics (f_0 and Q) of each of the second-order filter sections needed to synthesize a given higher-order filter. For the Chebyshev filter defined above, such a table yields the following characteristics:

f_{0A} = 529 Hz $\quad Q_A$ = 0.785

f_{0B} = 993 Hz $\quad Q_B$ = 3.559

For unity gain at dc, we also specify:

H_{0A} = 1

H_{0B} = 1

The desired clock-to-cutoff-frequency ratio for the overall filter of this example is 100 and a 100 kHz clock signal is available. Note that the required center frequencies for the two second-order sections will not be obtainable with clock-to-center-frequency ratios of 50 or 100. It will be necessary to adjust

$$\frac{f_{CLK}}{f_0}$$

externally. From *Table 1*, we see that Mode 3 can be used to produce a low-pass filter with resistor-adjustable center frequency.

In most filter designs involving multiple second-order stages, it is best to place the stages with lower Q values ahead of stages with higher Q, especially when the higher Q is greater than 0.707. This is due to the higher relative gain at the center frequency of a higher-Q stage. Placing a stage with lower Q ahead of a higher-Q stage will provide some attenuation at the center frequency and thus help avoid clipping of signals near this frequency. For this example, stage A has the lower Q (0.785) so it will be placed ahead of the other stage.

For the first section, we begin the design by choosing a convenient value for the input resistance: R_{1A} = 20k. The absolute value of the passband gain H_{OLPA} is made equal to 1 by choosing R_{4A} such that: $R_{4A} = -H_{OLPA}R_{1A} = R_{1A}$ = 20k. If the 50/100/CL pin is connected to mid-supply for nominal 100:1 clock-to-center-frequency ratio, we find R_{2A} by:

$$R_{2A} = R_{4A}\frac{f_{0A}^2}{(f_{CLK}/100)^2} = 2 \times 10^4 \times \frac{(529)^2}{(1000)^2} = 5.6k \text{ and}$$

$$R_{3A} = Q_A\sqrt{R_{2A}R_{4A}} = 0.785\sqrt{5.6 \times 10^3 \times 2 \times 10^4} = 8.3k$$

The resistors for the second section are found in a similar fashion:

$$R_{1B} = 20k$$

$$R_{4B} = R_{1B} = 20k$$

$$R_{2B} = R_{4B}\frac{f_{0B}^2}{(f_{CLK}/100)^2} = 20k\,\frac{(993)^2}{(1000)^2} = 19.7k$$

$$R_{3B} = Q_B\sqrt{R_{2B}R_{4B}} = 3.559\sqrt{1.97 \times 10^4 \times 2 \times 10^4} = 70.6k$$

The complete circuit is shown in *Figure 19* for split ±5V power supplies. Supply bypass capacitors are highly recommended.

3.0 Applications Information (Continued)

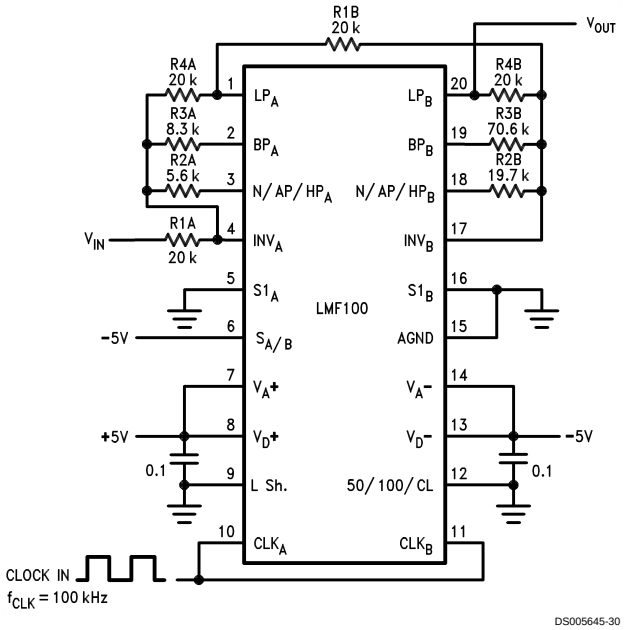


FIGURE 19. Fourth-order Chebyshev low-pass filter from example in 3.1. ±5V power supply. 0V–5V TTL or ±5V CMOS logic levels.

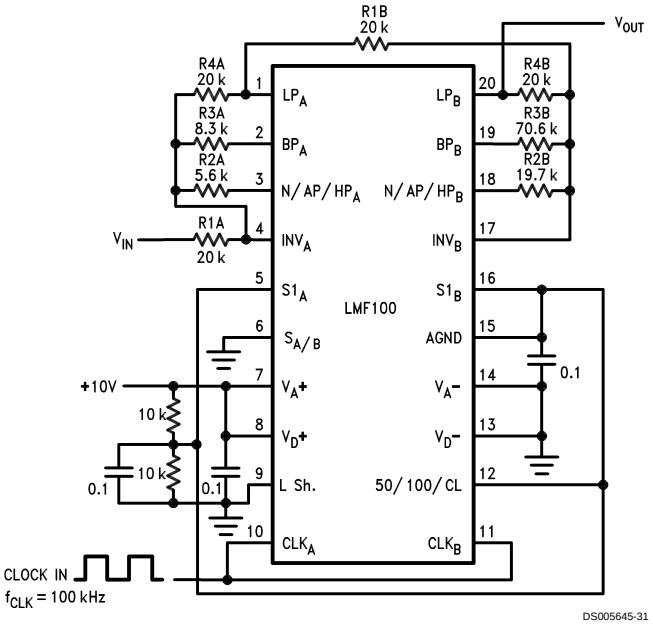
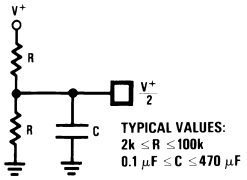
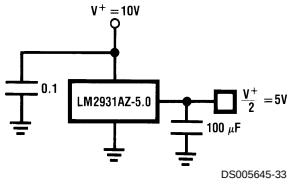


FIGURE 20. Fourth-order Chebyshev low-pass filter from example in 3.1. Single +10V power supply. 0V–5V TTL logic levels. Input signals should be referred to half-supply or applied through a coupling capacitor.

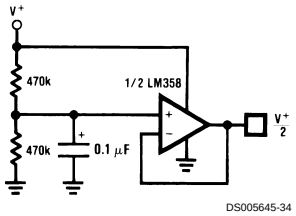
3.0 Applications Information (Continued)



(a) Resistive Divider with Decoupling Capacitor



(b) Voltage Regulator



(c) Operational Amplifier with Divider

FIGURE 21. Three Ways of Generating V+/2 for Single-Supply Operation

3.2 SINGLE SUPPLY OPERATION

The LMF100 can also operate with a single-ended power supply. *Figure 20* shows the example filter with a single-ended power supply. V_A+ and V_D+ are again connected to the positive power supply (4 to 15 volts), and V_A− and V_D− are connected to ground. The A_{GND} pin must be tied to $V^+/2$ for single supply operation. This half-supply point should be very "clean", as any noise appearing on it will be treated as an input to the filter. It can be derived from the supply voltage with a pair of resistors and a bypass capacitor (*Figure 21a*), or a low-impedance half-supply voltage can be made using a three-terminal voltage regulator or an operational amplifier (*Figure 21b* and *Figure 21c*). The passive resistor divider with a bypass capacitor is sufficient for many applications, provided that the time constant is long enough to reject any power supply noise. It is also important that the half-supply reference present a low impedance to the clock frequency, so at very low clock frequencies the regulator or op-amp approaches may be preferable because they will require smaller capacitors to filter the clock frequency. The main power supply voltage should be clean (preferably regulated) and bypassed with 0.1 µF.

3.3 DYNAMIC CONSIDERATIONS

The maximum signal handling capability of the LMF100, like that of any active filter, is limited by the power supply voltages used. The amplifiers in the LMF100 are able to swing to within about 1 volt of the supplies, so the input signals must be kept small enough that none of the outputs will exceed these limits. If the LMF100 is operating on ±5 volts, for example, the outputs will clip at about $8V_{p\text{-}p}$. The maximum input voltage multiplied by the filter gain should therefore be less than $8V_{p\text{-}p}$.

Note that if the filter Q is high, the gain at the lowpass or highpass outputs will be much greater than the nominal filter gain (*Figure 6*). As an example, a lowpass filter with a Q of 10 will have a 20 dB peak in its amplitude response at f_0. If the nominal gain of the filter (H_{OLP}) is equal to 1, the gain at f_0 will be 10. The maximum input signal at f_0 must therefore be less than 800 $mV_{p\text{-}p}$ when the circuit is operated on ±5 volt supplies.

Also note that one output can have a reasonable small voltage on it while another is saturated. This is most likely for a circuit such as the notch in Mode 1 (*Figure 7*). The notch output will be very small at f_0, so it might appear safe to apply a large signal to the input. However, the bandpass will have its maximum gain at f_0 and can clip if overdriven. If one output clips, the performance at the other outputs will be degraded, so avoid overdriving any filter section, even ones whose outputs are not being directly used. Accompanying *Figures 7, 8, 9, 10, 11, 12, 13, 14, 15, 16* and *Figure 17* are equations labeled "circuit dynamics", which relate the Q and the gains at the various outputs. These should be consulted to determine peak circuit gains and maximum allowable signals for a given application.

3.4 OFFSET VOLTAGE

The LMF100's switched capacitor integrators have a slightly higher input offset voltage than found in a typical continuous time active filter integrator. Because of National's new LMCMOS process and new design techniques the internal offsets have been minimized, compared to the industry standard MF10. *Figure 22* shows an equivalent circuit of the LMF100 from which the output dc offsets can be calculated. Typical values for these offsets with $S_{A/B}$ tied to V^+ are:

V_{OS1} = opamp offset = ±5 mV

V_{OS2} = ±30 mV at 50:1 or 100:1

V_{OS3} = ±15 mV at 50:1 or 100:1

When $S_{A/B}$ is tied to V^-, V_{OS2} will approximately halve. The dc offset at the BP output is equal to the input offset of the lowpass integrator (V_{OS3}). The offsets at the other outputs depend on the mode of operation and the resistor ratios, as described in the following expressions.

Mode 1 and Mode 4

$$V_{OS(N)} = V_{OS1}\left(\frac{1}{Q} + 1 + \left\|H_{OLP}\right\|\right) - \frac{V_{OS3}}{Q}$$

$$V_{OS(BP)} = V_{OS3}$$

$$V_{OS(LP)} = V_{OS(N)} - V_{OS2}$$

Mode 1a

$$V_{OS(N.INV.BP)} = \left(1 + \frac{1}{Q}\right) V_{OS1} - \frac{V_{OS3}}{Q}$$

$$V_{OS(INV.BP)} = V_{OS3}$$

$$V_{OS(LP)} = V_{OS(N.INV.BP)} - V_{OS2}$$

3.0 Applications Information

(Continued)

Mode 1b

$$V_{OS(N)} = V_{OS1}\left(1 + \frac{R2}{R3} + \frac{R2}{R1}\right) - \frac{R2}{R3}V_{OS3}$$

$$V_{OS(BP)} = V_{OS3}$$

$$V_{OS(LP)} = \frac{V_{OS(N)}}{2} - \frac{V_{OS2}}{2}$$

Mode 2 and Mode 5

$$V_{OS(N)} = \left(\frac{R2}{Rp} + 1\right) V_{OS1} \times \frac{1}{1 + R2/R4} + V_{OS2}\frac{1}{1+R4/R2} - \frac{V_{OS3}}{Q\sqrt{1+R2/R4}}:$$

$$R_p = R1 \| R3 \| R4$$

$$V_{OS(BP)} = V_{OS3}$$

$$V_{OS(LP)} = V_{OS(N)} - V_{OS2}$$

Mode 3

$$V_{OS(HP)} = V_{OS2}$$

$$V_{OS(BP)} = V_{OS3}$$

$$V_{OS(LP)} = V_{OS1}\left[1 + \frac{R4}{R_p}\right] - V_{OS2}\left(\frac{R4}{R2}\right) - V_{OS3}\left(\frac{R4}{R3}\right)$$

$$R_p = R1 \| R2 \| R3$$

Mode 6a and 6c

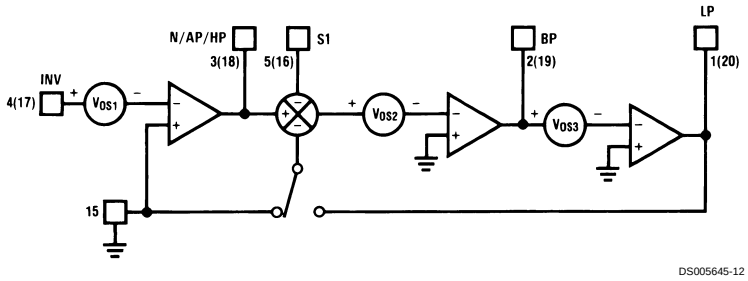
$$V_{OS(HP)} = V_{OS2}$$

$$V_{OS(LP)} = V_{OS1}\left(1 + \frac{R_3}{R_2} + \frac{R_3}{R_1}\right) - \frac{R_3}{R_2}V_{OS2}$$

Mode 6b

$$V_{OS(LP\ (N.INV))} = V_{OS2}$$

$$V_{OS(LP\ (INV))} = V_{OS1}\left(1 + \frac{R_3}{R_2}\right) - \frac{R_3}{R_2}V_{OS2}$$



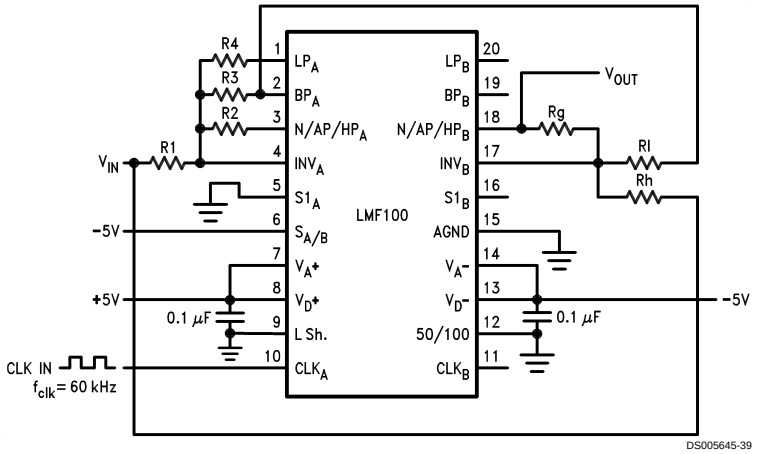
DS005645-12

FIGURE 22. Offset Voltage Sources

In many applications, the outputs are ac coupled and dc offsets are not bothersome unless large signals are applied to the filter input. However, larger offset voltages will cause clipping to occur at lower ac signal levels, and clipping at any of the outputs will cause gain nonlinearities and will change f_0 and Q. When operating in Mode 3, offsets can become excessively large if R_2 and R_4 are used to make f_{CLK}/f_0 significantly higher than the nominal value, especially if Q is also high.

For example, *Figure 23* shows a second-order 60 Hz notch filter. This circuit yields a notch with about 40 dB of attenuation at 60 Hz. A notch is formed by subtracting the bandpass output of a mode 3 configuration from the input using the unused side B opamp. The Q is 10 and the gain is 1 V/V in the passband. However, $f_{CLK}/f_0 = 1000$ to allow for a wide input spectrum. This means that for pin 12 tied to ground (100:1 mode), R4/R2 = 100. The offset voltage at the lowpass output (LP) will be about 3V. However, this is an extreme case and the resistor ratio is usually much smaller. Where necessary, the offset voltage can be adjusted by using the circuit of *Figure 24*. This allows adjustment of V_{OS1}, which will have varying effects on the different outputs as described in the above equations. Some outputs cannot be adjusted this way in some modes, however ($V_{OS(BP)}$ in modes 1a and 3, for example).

3.0 Applications Information (Continued)



R1 = 100 kΩ
R2 = 1 kΩ
R3 = 100 kΩ
R4 = 100 kΩ
Rg = 10 kΩ
Rl = 10 kΩ
Rh = 10 kΩ

FIGURE 23. Second-Order Notch Filter

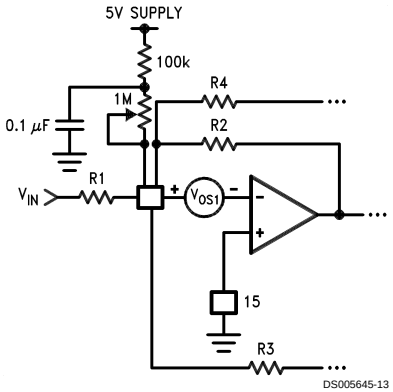


FIGURE 24. Method for Trimming V_{OS}

3.5 SAMPLED DATA SYSTEM CONSIDERATIONS

The LMF100 is a sampled data filter, and as such, differs in many ways from conventional continuous-time filters. An important characteristic of sampled-data systems is their effect on signals at frequencies greater than one-half the sampling frequency. (The LMF100's sampling frequency is the same as its clock frequency.) If a signal with a frequency greater than one-half the sampling frequency is applied to the input of a sampled data system, it will be "reflected" to a frequency less than one-half the sampling frequency. Thus, an input signal whose frequency is $f_s/2$ + 100 Hz will cause the system to respond as though the input frequency was $f_s/2$ − 100 Hz. This phenomenon is known as "aliasing", and can be reduced or eliminated by limiting the input signal spectrum to less than $f_s/2$. This may in some cases require the use of a bandwidth-limiting filter ahead of the LMF100 to limit the input spectrum. However, since the clock frequency is much higher than the center frequency, this will often not be necessary.

Another characteristic of sampled-data circuits is that the output signal changes amplitude once every sampling period, resulting in "steps" in the output voltage which occur at the clock rate (*Figure 25*). If necessary, these can be "smoothed" with a simple R-C low-pass filter at the LMF100 output.

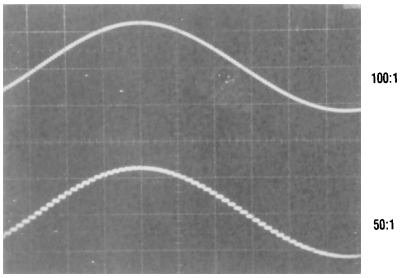
The ratio of f_{CLK} to f_c (normally either 50:1 or 100:1) will also affect performance. A ratio of 100:1 will reduce any aliasing problems and is usually recommended for wide-band input

3.0 Applications Information

(Continued)

signals. In noise-sensitive applications, a ratio of 100:1 will result in 3 dB lower output noise for the same filter configuration.

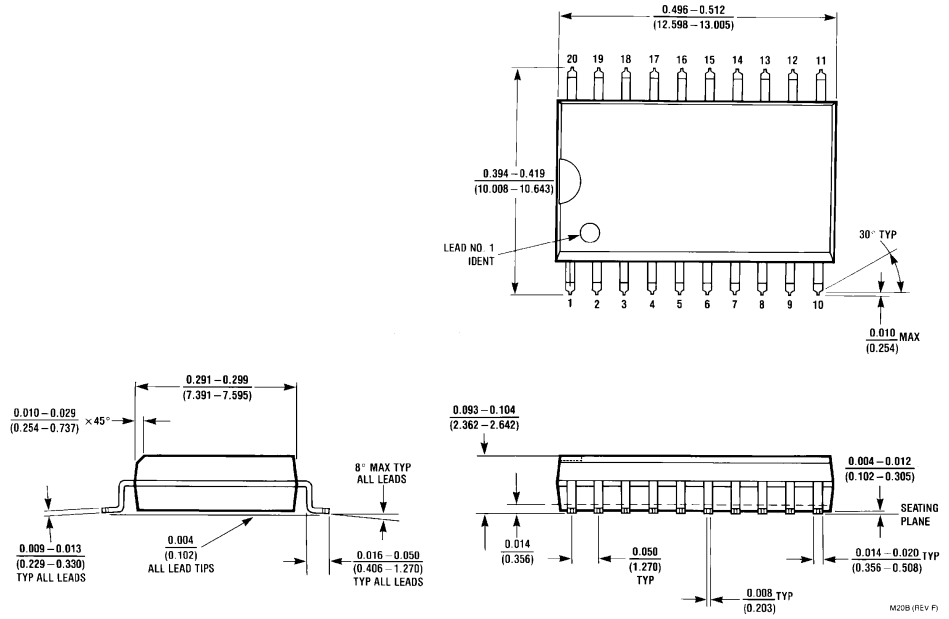
The accuracy of the f_{CLK}/f_0 ratio is dependent on the value of Q. This is illustrated in the curves under the heading “Typical Performance Characteristics”. As Q is changed, the true value of the ratio changes as well. Unless the Q is low, the error in f_{CLK}/f_0 will be small. If the error is too large for a specific application, use a mode that allows adjustment of the ratio with external resistors.



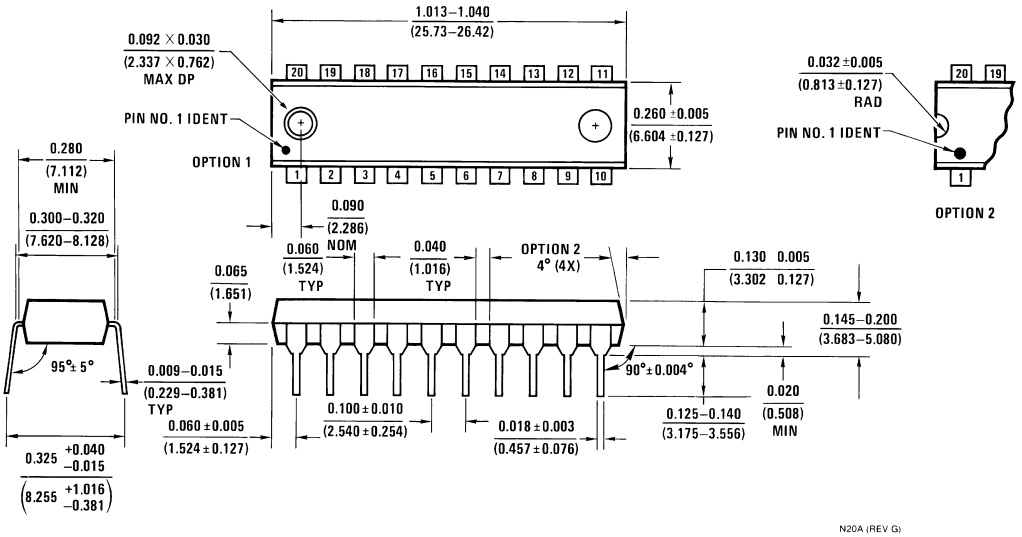
DS005645-35

FIGURE 25. The Sampled-Data Output Waveform

Physical Dimensions inches (millimeters) unless otherwise noted



Small Outline Package
Order Number LMF100CIWM
NS Package Number M20B



Molded Dual-In-Line Package (N)
Order Number LMF100CCN
NS Package Number N20A

Notes

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